

THYRISTOR-DIODE MODULE | 可控硅-二极管混合模块

Features

- Base & chip insulation AC voltage 2500V
- International standard packing
- Excellent temperature feature
- ≥300A could chose water-cool
- Easy to install

Explanation

- I_{GT}, V_{GT}, I_H are all $T_A=25^\circ C$ test data, others are all $T_A=T_{jm}$ test data.
- $I^2t = I_{TSM}^2 \times t_w / 2$: t_w = Half sine wave current, when at 50Hz,
 $I^2t = 0.005 I_{TSM}^2 (A^2S)$
- When at 60Hz, $I_{TSM}(8.3ms) = I_{TSM}(10ms) \times 1.066, T_j = T_{jm}$
 $I^2t(8.3ms) = I^2t(10ms) \times 0.943, T_j = T_{jm}$

Applications

- AC DC motor control
- Motor soft start
- Industry heat-up control
- Rectificate power supply
- Welder
- Frequency transformer
- UPS power supply
- Battery charge & discharge

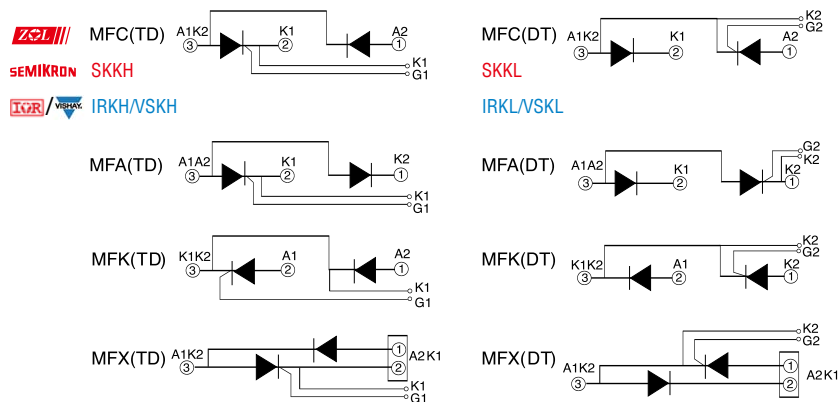
Ordering Information Table

Device Code **M F C 160 -12 ***

① ② ③ ④ ⑤ ⑥

- 1 -Power Module
- 2 -T=thy-thy;D=dio-dio;F=dio-thy;
K=fast thy;Z=fast dio;H=fast thy-fast dio
- 3 -Circuit form:A=common positive pole;
C=series connection;
K=common negative pole;
X=reverse parallel connection;
- 4 -Current Code= $I_{F(AV)}/I_{T(AV)}$
- 5 -Voltage code=Code $\times 100 = V_{RRM}$
- 6 -None: Air-cool * Means water-cool

Part number type & circuit



THYRISTOR-DIODE MODULE 可控硅-二极管混合模块 (MFC,MFK,MFA,MFX)

Type	$I_{T(AV)}$	$V_{DRM} V_{RRM}$	$V_{TM@I_{TM}}$		$I_{DRM} I_{RRM}$	I_{GT}	V_{GT}	I_H	d_v/d_t	d/d_t	I_{TSM}	R_{jc}	T_{jm}	V_{iso}	Outline
	A	V	V	A	mA	mA	V	mA	V/ μs	A/ μs	$A \times 10^3$	$^\circ C/W$	$^\circ C$	V(AC)	
MFXT25A	25	400-2600	1.69	80	8	100	2.5	100	800	50	0.55	0.950	125	2500	M1/M2
MFXT40A	40	400-2600	1.60	120	8	100	2.5	100	800	50	1.00	0.650	125	2500	M1/M2
MFXT55A	55	400-2600	1.50	170	8	100	2.5	100	800	50	1.25	0.530	125	2500	M1/M2
MFXT70A	70	400-2600	1.48	210	10	100	2.5	100	800	50	1.60	0.410	125	2500	M1/M2
MFXT90A	90	400-2600	1.94	270	15	100	2.5	100	800	100	2.00	0.280	125	2500	M1/M2
MFXT110A	110	400-2600	1.90	330	20	100	2.5	100	800	100	2.40	0.250	125	2500	M1/M2
MFXT130A	130	400-2600	1.96	410	25	150	2.5	100	800	100	3.80	0.200	125	2500	M2/M3
MFXT160A	160	400-2600	1.90	480	25	150	2.5	100	800	100	5.40	0.170	125	2500	M3
MFXT200A	200	400-2600	1.90	600	30	180	2.5	100	800	100	7.20	0.140	125	2500	M3/M4
MFXT250A	250	400-2600	1.73	750	30	180	2.5	100	800	100	8.50	0.120	125	2500	M4
MFXT300A	300	400-2600	1.58	900	40	180	2.5	100	800	100	9.30	0.100	125	2500	M4
MFXT350A	350	400-2600	1.45	1050	40	180	2.5	100	800	100	11.0	0.090	125	2500	M5
MFXT400A	400	400-2600	1.44	1200	40	200	3.0	100	800	100	14.0	0.080	125	2500	M5
MFXT500A	500	400-2600	1.44	1500	40	200	3.0	100	800	100	16.0	0.065	125	2500	M5
MFXT300A*	300*	400-2600	1.60	900	40	180	2.5	100	800	100	9.30	0.100	125	2500	M6
MFXT500A*	500*	400-2600	1.65	1500	40	200	3.0	100	800	100	11.0	0.087	125	2500	M7
MFXT600A*	600*	400-2600	1.70	1800	40	200	3.0	100	800	100	13.0	0.073	125	2500	M7/M8
MFXT800A*	800*	400-2600	1.75	2400	40	200	3.0	100	800	100	16.0	0.054	125	2500	M8
MFXT1000A*	1000*	400-2600	1.95	3000	40	200	3.0	100	800	100	20.0	0.050	125	2500	M9

*Means water-cool

STUD VERSION SEMICONDUCTOR
 CAPSULE VERSION SEMICONDUCTOR
 POWER MODULES
 BRIDGE RECTIFIER
 SILD STATE RELAY & PRESS-FIT DIODE
 SUBASSEMBLY HEATSINK
 WELDING ACCESSORIES